

### VSIB4A20 thru VSIB4A80

Vishay General Semiconductor

# Single-Phase Single In-Line Bridge Rectifier



PRIMARY CHARACTERISTICS					
I <sub>F(AV)</sub>	4.0 A				
V <sub>RRM</sub>	200 V to 800 V				
I <sub>FSM</sub>	80 A				
I <sub>R</sub>	5 μΑ				
V <sub>F</sub>	1.0 V				
T <sub>.I</sub> max.	150 °C				

### **FEATURES**





· Ideal for printed circuit boards

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RoHS

High surge current capability

- High case dielectric strength of 1500  $V_{RMS}$
- Solder dip 260 °C, 40 s
- Compliant to RoHS directive 2002/95/EC and in accordance to WEEE 2002/96/EC

### **TYPICAL APPLICATIONS**

General purpose use in ac-to-dc bridge full wave rectification for monitor, TV, printer, switching mode power supply, adapter, audio equipment, and home appliances applications.

#### **MECHANICAL DATA**

Case: GSIB-3S

Epoxy meets UL 94 V-0 flammability rating

Terminals: Matte tin plated leads, solderable per

J-STD-002 and JESD 22-B102

E3 suffix for consumer grade, meets JESD 201 class

1A whisker test

**Mounting Torque:** 10 cm-kg (8.8 inches-lbs) max. **Recommended Torque:** 5.7 cm-kg (5 inches-lbs)

MAXIMUM RATINGS (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	SYMBOL	VSIB4A20	VSIB4A40	VSIB4A60	VSIB4A80	UNIT		
Maximum repetitive peak reverse voltage	$V_{RRM}$	200	400	600	800	V		
Maximum RMS voltage	V <sub>RMS</sub>	140	280	420	560	V		
Maximum DC blocking voltage	$V_{DC}$	200	400	600	800	V		
$ \begin{array}{ll} \text{Maximum average forward} & T_{\text{C}} = 100  ^{\circ}\text{C} \\ \text{rectified output current at} & T_{\text{A}} = 25  ^{\circ}\text{C} \\ \end{array} $	I <sub>F(AV)</sub>	4.0 <sup>(1)</sup> 2.3 <sup>(2)</sup>				Α		
Peak forward surge current single sine-wave superimposed on rated load	I <sub>FSM</sub>	80			Α			
Rating for fusing (t < 8.3 ms)	I <sup>2</sup> t	32			A <sup>2</sup> s			
Operating junction and storage temperature range	T <sub>J</sub> , T <sub>STG</sub>	- 55 to + 150			°C			

#### Notes

<sup>(1)</sup> Unit case mounted on aluminum plate heatsink

 $<sup>^{(2)}</sup>$  Units mounted on P.C.B. with 0.5" x 0.5" (12 mm x 12 mm) copper pads and 0.375" (9.5 mm) lead length

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<b>ELECTRICAL CHARACTERISTICS</b> (T <sub>A</sub> = 25 °C unless otherwise noted)								
PARAMETER	TEST CONDITIONS		SYMBOL	VSIB4A20	VSIB4A40	VSIB4A60	VSIB4A80	UNIT
Maximum instantaneous forward drop per diode <sup>(1)</sup>	I <sub>F</sub> = 2.0 A	T <sub>A</sub> = 25 °C	V <sub>F</sub>	1.0			V	
Maximum reverse current per diode (2)	Rated V <sub>R</sub>	T <sub>A</sub> = 25 °C T <sub>A</sub> = 125 °C	I <sub>R</sub>	5.0 200			μА	

#### **Notes**

 $^{(1)}$  Pulse test: 300  $\mu s$  pulse width, 1 % duty cycle

(2) Pulse test: Pulse width ≤ 40 ms

THERMAL CHARACTERISTICS (T <sub>A</sub> = 25 °C unless otherwise noted)						
PARAMETER		VSIB4A20	VSIB4A40	VSIB4A60	VSIB4A80	UNIT
Maximum thermal resistance	$egin{array}{l} {\sf R}_{ heta {\sf JA}} \ {\sf R}_{ heta {\sf JC}} \end{array}$	26 <sup>(2)</sup> 5 <sup>(1)</sup>			°C/W	

#### **Notes**

(1) Unit case mounted on aluminum plate heatsink

(2) Units mounted on P.C.B. with 0.5" x 0.5" (12 mm x 12 mm) copper pads and 0.375" (9.5 mm) lead length

<sup>(3)</sup> Recommended mounting position is to bolt down on heatsink with silicone thermal compound for maximum heat transfer with #6 screw

ORDERING INFORMATION (Example)							
PREFERRED P/N	UNIT WEIGHT (g)	PREFERRED PACKAGE CODE	BASE QUANTITY	DELIVERY MODE			
VSIB4A60-E3/45	4.0	45	20	Tube			

### **RATINGS AND CHARACTERISTICS CURVES**

(T<sub>A</sub> = 25 °C unless otherwise noted)

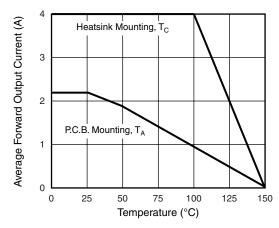


Figure 1. Derating Curve Output Rectified Current

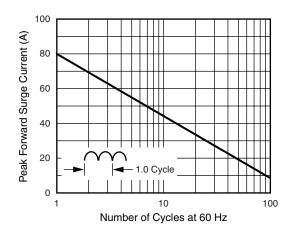


Figure 2. Maximum Non-Repetitive Peak Forward Surge Current Per Diode





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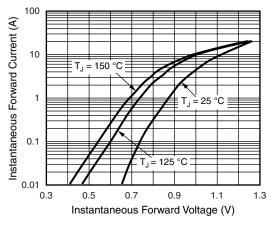


Figure 3. Typical Forward Characteristics Per Diode

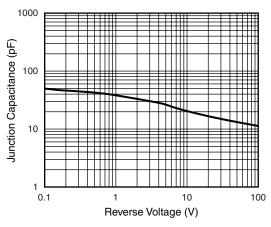


Figure 5. Typical Junction Capacitance Per Diode

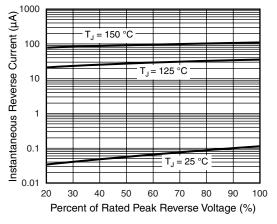


Figure 4. Typical Reverse Characteristics Per Diode

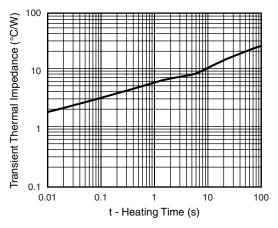
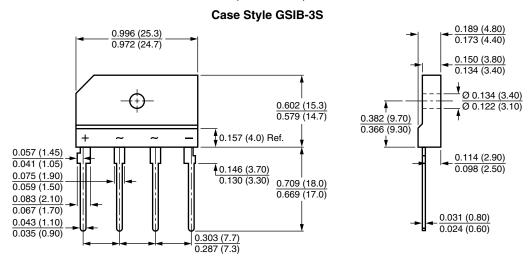


Figure 6. Typical Transient Thermal Impedance Per Diode

### **PACKAGE OUTLINE DIMENSIONS** in inches (millimeters)





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